TSMC 16/12: 3.3V 100MHz Oscillators



Libraries

Name	Process	Form Factor
RGO_TSMC16_18V33_FFC_20C_OSC	FFC	Staggered CUP
RGO_TSMC12_18V33_FFC_LL_20C_OSC	FFC_LL	Staggered CUP

Summary

The $3.3V\ 100MHz$ Oscillators library includes a programmable oscillator macro I/O cell.

100 MHz programmable oscillator

These libraries are offered at both 16nm and a 12nm shrink. They are available in a staggered CUP wire bond implementation with a flip chip option.

To utilize these cells in the pad ring, an additional library is required – 3.3V Support: Power. That library contains the DVDD/DVSS power cells necessary for ESD protection, the POC and VREF cells, and a rail splitter to isolate the oscillator in its own power domain as recommended. It also contains an input-only buffer, isolated analog I/O, and a full complement of power cells along with corner and spacer cells to assemble a complete pad ring by abutment. The rail splitter allows multiple power domains to be isolated in the same pad ring while maintaining continuous VDD/VSS for robust ESD protection.

ESD Protection:

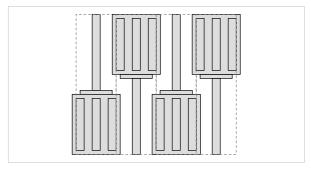
- JEDEC compliant
 - o 2KV ESD Human Body Model (HBM)
 - 500 V ESD Charge Device Model (CDM)

Latch-up Immunity:

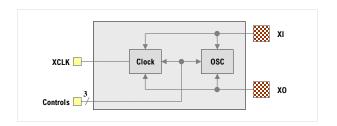
- JEDEC compliant
 - o Tested to I-Test criteria of ± 100mA @ 125°C

Cell Size & Form Factor

Staggered (pad-limited) - 100.8 µm x 165.024 µm



OSP BI 100 1833V



100 MHz Programmable Oscillator Features

- Programmable drive strength for wider frequency range 1 MHz to 100 MHz using industry standard external crystals.
- Optimized for stability and minimum jitter
- Power-down mode
- Operates on core power only (VDD/VSS cells embedded)

Vertical-only (_V) and and horizontal-only (_H) variants provided.

Recommended operating conditions

	Description	Min	Nom	Max	Units
V _{VDD}	Core supply voltage	0.72	0.80	0.88	V
V _{DVDD}	I/O supply voltage	2.97	3.3	3.63	V
		2.25	2.5	2.75	V
		1.62	1.8	1.98	V
		1.08	1.2	1.32	V
TJ	Junction temperature	-40	25	125	°C
V _{PAD}	Voltage at XI [1]	0	-	V_{VDD}	V

[1] XI can be driven by an external clock for bypass operation. XO should never be driven or loaded by anything other than the oscillator crystal.

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Characterization Corners (16nm)

Model	LPE Type	VDD=0.8V	DVDD [1]	Temp	
FFGNP	Cbest_CCbest_T	+10%	+10%	-40°C	
FFGNP	Cbest_CCbest_T	+10%	+10%	0°C	
FFGNP	Cbest_CCbest_T	+10%	+10%	125°C	
FFG	Ctypical	+10%	+10%	125°C	
TT	Ctypical	nominal	nominal	25°C	
TT	Ctypical	nominal	nominal	85°C	
SSGNP	Cworst_CCworst_T	-10%	-10%	-40°C	
SSGNP	Cworst_CCworst_T	-10%	-10%	0°C	
SSGNP	Cworst_CCworst_T	-10%	-10%	125°C	
[1] DVDD = 3.3V, 2.5V, 1.8V & 1.2V.					

Characterization Corners (12nm)

Model	LPE Type	VDD=0.8V	DVDD [1]	Temp
FF	Cbest_CCbest	+10%	+10%	-40°C
FF	Cbest_CCbest	+10%	+10%	0°C
FF	Cbest_CCbest	+10%	+10%	125°C
FFG	Ctypical	+10%	+10%	125°C
TT	Ctypical	nominal	nominal	25°C
TT	Ctypical	nominal	nominal	85°C
SS	Cworst_CCworst	-10%	-10%	-40°C
SS	Cworst_CCworst	-10%	-10%	0°C
SS	Cworst_CCworst	-10%	-10%	125°C

[1] DVDD = 3.3V, 2.5V, 1.8V & 1.2V.

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